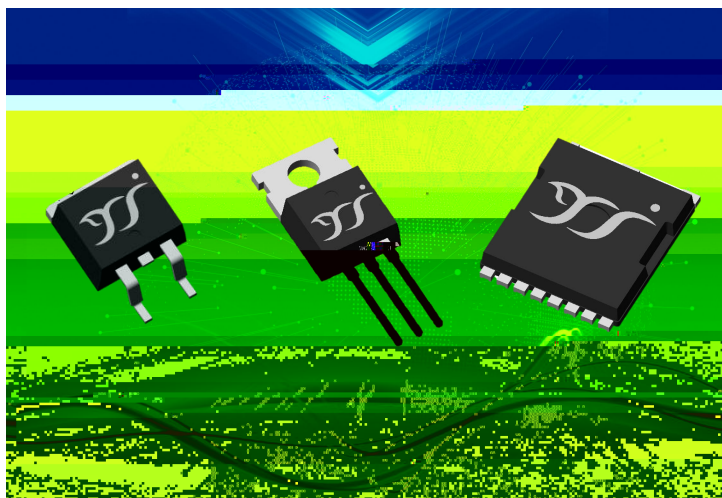




TOLL 53' TO 20 MS
MOS P+SAS..q\$!w ep





- 1.The product utilizes optimized SGT technology, featuring low on-resistance and excellent switching performance.
- 2.It is available in packages such as TOLL TO-263 TO-220 and is suitable for high-power applications such as BMS.
- 3.For various working states of industrial control applications, optimize the EAS capability of MOS products to enhance their reliability.

Please refer to the official website for more details

Product Name	Package	Vds V	ID A	Vth V typ.	Rds10V mohm typ.	Rds10V mohm max.	Og10V nC typ.	Tj	N/P
YJT2D0G06H	TOLL	60	250	3	1.62	2	81.1	-55-175	N
YJB2D3G06H	TO-263	60	220	3	1.84	2.3	79	-55-175	N

YangJie technology recently launched a series of N60V MOSFET products for clean energy. The products adopt specially optimized SGT technology, with low Rdson and Qg, significantly reducing forward voltage drop and switching losses while enhancing the MOSFET's resistance to inrush current

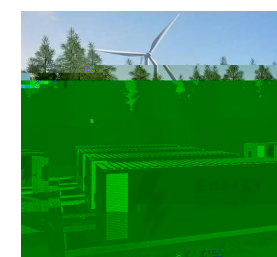
New Product Launch



BMS



DC-DC



Energy Storage